

Hall Effect Measurement System HALL 8800



Features:

- Ohmic contact check
- Large concentration and resistivity range
- Measurement offset compensation
- · Flexible, modular hardware
- Simplicity and accuracy operation software
- Compact and easy-to-use desktop system

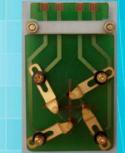
THINK SMART, THINK SWIN

Applications:

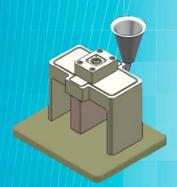
The Swin HALL 8800 Hall effect measurement system combines HALL effect measurement with van der pauw method four-point measurement to decide the characteristic such as resistivity ρ, carrier concentration N (N Type & P Type), and mobility μ of various material including Si, Ge, SiGe, SiC, GaAs, InGaAs, InP, GaN, ZnO, Graphene etc. at both 300K and 77K for scientific research, education, production applications.

Specifications:

- Sample size: 10 mm x 10 mm ~ 15 mm x 15 mm
- Measurement Temperature: RT (room temperature ~ 300K) and 77 K
- Measurement Material: Material such as Si, SiGe, SiC, GaAs, InGaAs, InP, GaN, ZnO, Graphene etc..
- Magnet : Permanent magnet (diameter: 30 mm)
- Magnet Flux Density: 0.48T ~ 1T(depends on application)
- Stability: 2% over 1 years
- Uniformity: +/- 1% over 20 mm diameter from center
- Resistivity: 10⁻⁵ ~ 10⁷ (Ω-cm)
- Mobility: 1 ~ 10⁷ (cm² / Volt-sec)
- Carrier Concentration: 10⁷ ~ 10²¹ (cm⁻³) (N Type & P Type)
- Output current: 2nA ~ 100mA
- Input Voltage: 1µV ~300V
- Dimensions (L/W/H): 400 mm x 360 mm x 200 mm
- Weight: 12 kgw (with package)



Sample board (Spring clip structure)



Room temperature & 77K measurement kit



Room temperature measurement kit



For mounting thin samples



For mounting thicker samples

93S

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